15C01M



Bipolar Transistor 15V, 0.7A, Low VCE(sat) NPN Single MCP

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Applications

· Low-frequency Amplifier, muting circuit

Features

- · Large current capacity
- · Low collector-to-emitter saturation voltage (resistance) RCE (sat) typ.=0.58Ω [IC=0.7A, IB=35mA]
- · Ultrasmall package facilitates miniaturization in end products
- · Small ON-resistance (Ron)

Specifications

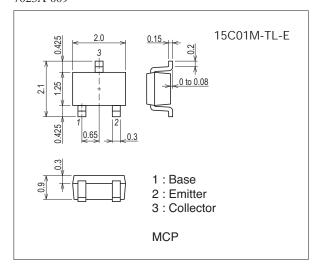
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		20	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		700	mA
Collector Current (Pulse)	ICP		1.4	А
Collector Dissipation	PC	Mounted on a glass epoxy board (20×30×1.6mm)	300	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7023A-009

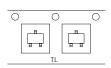


Product & Package Information

• Package : MCP

• JEITA, JEDEC : SC-70, SOT-323 • Minimum Packing Quantity : 3,000 pcs./reel

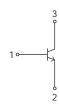
Packing Type: TL



Marking



Electrical Connection

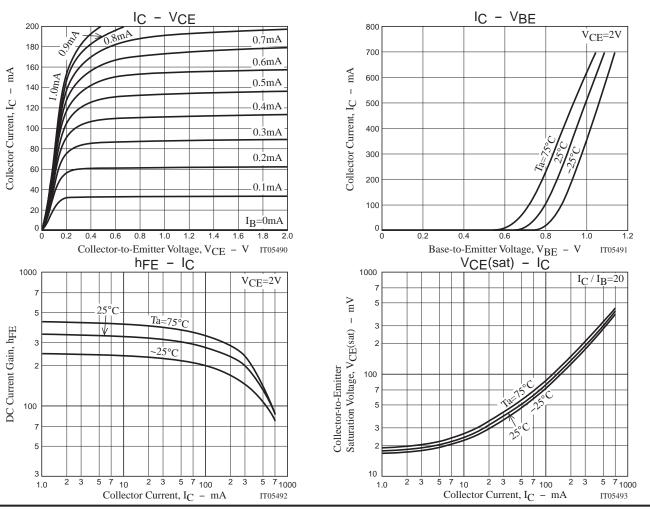


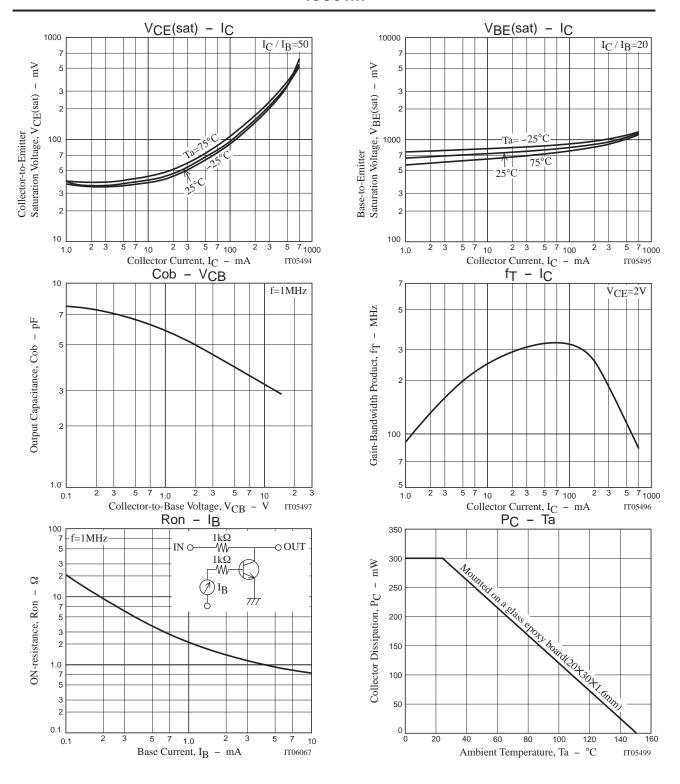
Electrical Characteristics at Ta=25°C

Parameter	Cymphal	Conditions	Ratings			Linit	
Parameter	Symbol	Conditions	min	typ	max	Unit	
Collector Cutoff Current	ICBO	V _{CB} =15V, I _E =0A			0.1	μΑ	
Emitter Cutoff Current	I _{EBO}	V _{EB} =4V, I _C =0A			0.1	μΑ	
DC Current Gain	hFE	V _{CE} =2V, I _C =10mA	300		800		
Gain-Bandwidth Product	fT	V _{CE} =2V, I _C =50mA		330		MHz	
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		3.2		pF	
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =200mA, I _B =10mA		150	300	mV	
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =200mA, I _B =10mA		0.9	1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0A	20			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	15			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0A	5			V	
Turn-On Time	ton			30		ns	
Storage Time	tstg	See specified Test Circuit.		77		ns	
Fall Time	tf			40		ns	

Ordering Information

Device Package		Shipping	memo	
15C01M-TL-E	MCP	3,000pcs./reel	Pb Free	



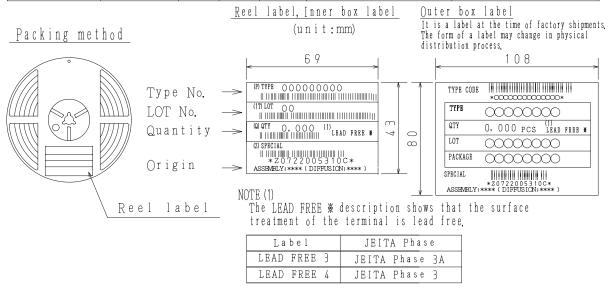


Embossed Taping Specification

15C01M-TL-E

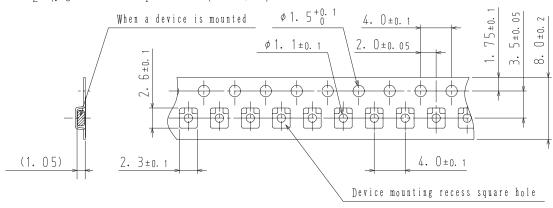
1. Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing	format		
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)		
MCP	MCP	3, 000	15, 000	90,000	5 reels contained	6 inner boxes contained		
					Dimensions:mm (external)	Dimensions:mm (external)		
					183×72×185	440×195×210		

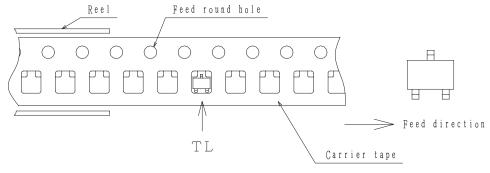


2. Taping configuration

2-1. Carrier tape size (unit:mm)



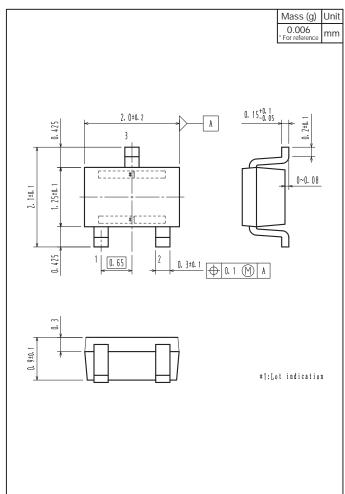
2-2. Device placement direction



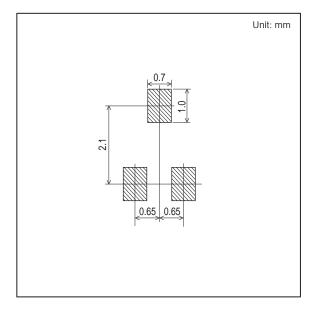
Those with oen electrode terminal on the feed hole side·····TL

Outline Drawing

15C01M-TL-E



Land Pattern Example



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